

2.4GHz TO 2.5GHz, 802.11b/g/n SINGLE-BAND FRONT END MODULE

Package Style: QFN, 16-pin, 3.0 x 3.0 x 0.5 mm



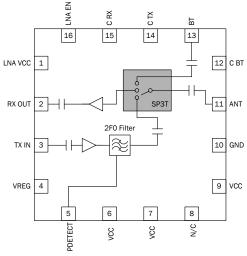


Features

- Single Module Radio Front-End
- Single Supply Voltage 3.0V to 4.5V
- Integrated 2.4GHz to 2.5GHz PA, LNA, TX/RX Switch, PDETECT
- 24dBm Output Power for Zigbee® Applications
- 20dBm Output Power for 11b Meeting Spectral Mask
- 17 dBm Output Power for 11g, 54 Mbps OFDM at < 3% EVM

Applications

- ZigBee® Based Systems for Remote Monitoring and Control
- Smart Meters for Energy Management
- 802.11b/g WiFi Applications
- 2.5GHz ISM Band Applications
- Portable Battery-Powered Equipment
- Opt. Bluetooth[™] Sharing of Single Antenna Port



Functional Block Diagram

Product Description

The RF5745 is a single-chip integrated front-end module (FEM) for high-performance ZigBee® and other WiFi applications in the 2.4GHz to 2.5GHz ISM band. The FEM addresses the need for aggressive size reduction for a typical IEEE802.15.4 and IEEE802.11b/g systems.

The RF5745 greatly reduces the number of external components by integrating all matching networks. The FEM has an integrated power amplifier, LNA, power detector, and some TX filtering. It is also capable of switching between WiFi RX, WiFi TX and *Bluetooth*TM RX/TX operations. The device is provided in a 3mmx3mmx0.45mm, 16-pin QFN package. This module meets or exceeds the front-end system requirements for and WiFi applications.

Ordering Information

RF5745 Standard 25 piece bag RF5745SR Standard 100 piece reel RF5745TR7 Standard 2500 piece reel

RF5745PCK-410 Fully assembled evaluation board tuned for 2.4 GHz to

2.5 GHz and 5 piece loose samples

Optimum Technology Matching® Applied

☐ GaAs HBT ☐ SiGe	DICIVIOS LE GAAS	pHEMT 🔲 GaN HEMT
GaAs MESFET Si Bi	CMOS Si CM	OS
✓ InGaP HBT ☐ SiGe	HBT ☐ Si BJT	



Absolute Maximum Ratings

Parameter	Pating	Unit
Farameter	Rating	Offic
DC Supply Voltage	5.0	V
DC Supply Current	240	mA
Full Specification Temp Range (Full Spec. Compliant)	-15 to +65	°C
Extreme Operating (Reduced Performance)	+65 to +85 -40 to -15	°C
Storage Temperature	-40 to +150	°C
Antenna Port Nominal Impedance	50	Ω
Maximum TX Input Power for 11b/g/IEEE802.15.4 (No Damage)	+5	dBm
Moisture Sensitivity	MSL2	



Exceeding any one or a combination of the Absolute Maximum Rating conditions may cause permanent damage to the device. Extended application of Absolute Maximum Rating conditions to the device may reduce device reliability. Specified typical performance or functional operation of the device under Absolute Maximum Rating conditions is not implied.

RoHS status based on EUDirective 2002/95/EC (at time of this document revision).

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Davamatav	Specification			11	O and diking	
Parameter	Min. Typ.		Max.	Unit	Condition	
2.4 GHz Transmit Parameters						
Compliance					IEEE802.11b, IEEE802.11g, IEEE802.15.4, FCC CFG 15.247, .205, .209	
Nominal Conditions					V _{CC} =4.0V, V _{REG} =2.85V pulsed at 1% to 100% duty cycle, Temp=+25°C, Freq=2.4GHz to 2.5GHz, unless otherwise noted	
Frequency	2.4		2.5	GHz		
Output Power						
ZigBee® (IEEE802.15.4)		24		dBm	Measured with ZigBee® Waveform	
11g	15	17		dBm	At rated 11g power, over Temp range, V _{CC} =4.0V, V _{REG} =2.85, over Frequency, and over Process. 54 Mbps, OFDM, 64QAM	
IEEE802.11b	19	20		dBm	Measured at 1 Mbps meeting ACP1/ACP2 requirements	
EVM*		3.0	4.0	%	RMS, mean, P _{OUT(g)} =17 dBm	
Adjacent Channel Power						
ACP1		-34	-30	dBc	At rated 11b power, over Temperature range, over V _{CC} , over Frequency, and over Process	
ACP2		-53	-50	dBc	At rated 11b power, over Temperature range, over V _{CC} , over Frequency, and over Process	
Gain	29	31		dB		
Gain Variation						
Frequency	-1		+1	dB	2.4 GHz to 2.5 GHz	

^{*}The EVM specification is obtained with a signal generator that has an EVM level <0.7%.



Parameter	Specification			Unit	Condition		
Faranietei	Min.	Тур.	Max.	Unit	Condition		
2.4 GHz Transmit Parameters,							
cont'd							
Power Detect							
Voltage Detect	0.1		2.0	V	P _{OUT} 0dBm to 23dBm over all conditions		
Input Resistance		10		kΩ			
Input Capacitance			5	pF			
Bandwidth	800	1000		kHz			
Current Consumption							
I _{cc}		150		mA	RFP _{OUT} =16dBm, 54Mbps IEEE802.11g		
		190			At rated 11b power		
		250		mA	RFPOUT=24dBm, 11b and ZigBee® waveform		
Idle		110		mA	V _{CC} =4V, V _{REG} =2.85V, and RF=0FF		
I _{REG}		3	5	mA			
Leakage		2	10	μА			
Power Supply	3.0	4	4.5	V			
V _{REG}	2.75	2.85	2.95	V			
Input/Output Impedance		50		Ω			
Ruggedness							
Output VSWR	10:1				No damage		
Stability							
Output VSWR	5:1				No spurs above -45 dBm/MHz		
Thermal Resistance		79.25		°C/W	V _{CC} = 3.3, V _{REG} = 2.9V, C_TX = 3.3,		
					C_RX = C_BT = GND, P _{OUT} = 17dBm,		
					Modulation = On, Freq = 2.45GHz, DC = 100%, T = 85°C		
Harmonics					RBW=1MHz. Measured at 1Mbps.		
Second		-27	TBD	dBm	P _{OUT} at CF=20dBm, H2 Frequency is between		
					4.8 GHz to 5.0 GHz		
Third		-48	TBD	dBm	P _{OUT} at CF=20dBm, H3 Frequency is between 7.2GHz to 7.5GHz		
Turn-On/Off Time		0.5	1.0	μS	Output stable to within 90% of final gain		
Antenna Port Impedance					Antenna port is a DC short to ground		
Input		50		Ω	Receive		
Output		50		Ω	Transmit		
Switch Control Voltage							
Low		0	0.2	V			
High	2.30	2.85	V _{CC}	V			
Switch Control Current			10	μА	Per control line		
Switch Control Speed		100		nsec			
		!			I .		



Specification			Unit	Condition	
Min.	Тур.	Max.	Unit	Condition	
2.4		2.5	GHz		
	12		dB	WiFi RX mode only	
<u> </u>	8		dB	WiFi RX and BT RX mode	
<u> </u>	2.5		dB	WiFi RX mode only	
	8		dB	WiFi RX and BT RX mode	
-1		+1	dB		
9.6			dB		
<u> </u>	50		Ω	No external matching	
<u> </u>	10	13	mA		
	+9		dBm		
2.4		2.5	GHz		
	1.2		dB	SP3T switch, all unused ports terminated into	
Ì				their nominal impedance. <i>Bluetooth</i> TM mode only	
	5		dB	WiFi RX and BT RX mode	
-0.2		+0.2	dB		
1		8	dBm		
9.6			dB		
	50		Ω	No external matching	
1		30	μΑ	Switch leakage current	
	2.4 -1 9.6 2.4	Min. Typ. 2.4 12 8 2.5 8 -1 9.6 50 10 +9 2.4 1.2 5 -0.2	Min. Typ. Max. 2.4 2.5 12 8 2.5 8 -1 +1 9.6 50 10 13 +9 2.4 2.5 1.2 5 -0.2 +0.2 8 9.6 50	Min. Typ. Max. 2.4 2.5 GHz 12 dB 8 dB 2.5 dB 8 dB -1 +1 dB 9.6 dB 50 Ω 10 13 mA +9 dBm 2.4 2.5 GHz 1.2 dB -0.2 +0.2 dB 8 dBm 9.6 dB 50 Ω	

^{*}The EVM specification is obtained with a signal generator that has an EVM level <0.7%.

Isolation Table

Parameter	Min.	Тур.	Max.	Unit
WiFi RX to BT RX/TX	20			dB
WiFi TX to BT RX/TX	20			dB
WiFi RX to WiFi TX	20			dB
WiFi RX and BT RX Mode	9			dB

Switch Control Logic

<u> </u>			
Mode	C_RX	C_TX	C_BT
Bluetooth TM	L	L	Н
WiFi Tx	L	Н	L
WiFi Rx	Н	L	L
WiFi Rx/BT	Н	L	Н

^{*}The FEM can simultaneously receive WiFi and BluetoothTM in the WiFi RX and BT RX Mode.



Pin	Function	Description
1	LNA VCC	Voltage supply for the LNA.
2	RX OUT	Receive port for 802.11b/g band. Internally matched to 50Ω . DC block provided.
3	TX	RF input for the 802.11b/g PA. Input is matched to 50Ω and DC block is provided.
4	VREG	Regulated voltage for the PA bias control circuit. An external bypass capacitor may be needed on the V_{REG} line for decoupling purposes.
5	PDETECT	Power detector voltage for TX section. PDET voltage varies with output power. May need external decoupling capacitor for module stability. May need external circuitry to bring output voltage to desired level.
6	VCC	Supply voltage for the bias circuit of the PA. Add an external 56pF bypass capacitor for low frequency decoupling.
7	VCC	Supply voltage for the first stage of the PA. Add an external 1nF capacitor for low frequency decoupling.
8	N/C	No connect.
9	VCC	Supply voltage for the second stage of the PA. Add an external 10nF capacitor for low frequency decoupling.
10	GND	Ground.
11	ANT	Port matched to 50Ω and is a DC short to ground.
12	C_BT	Switch control port. See truth table for proper level.
13	ВТ	RF bidirectional port for Bluetooth TM . Input is matched to 50Ω and DC block is provided.
14	C_TX	Switch control port. See switch truth table for proper level.
15	C_RX	Switch control port. See switch truth table for proper level.
16	LNA_EN	LNA enable pin. This is an active high control. An external bypass capacitor may be needed on the LNA_EN line.

Package Drawing

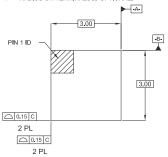
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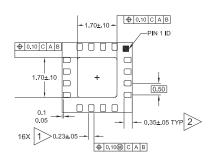
1) DIMENSION APPLIES TO METALLIZED TERMINAL AND IS MEASURED BETWEEN 0.25mm AND 0.30mm FROM TERMINAL TIP.

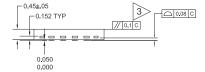
DIMENSION REPRESENTS TERMINAL PULL BACK FROM PACKAGE EDGE UP TO 0.1mm IS ACCEPTABLE.

3 COPLANARITY APPLIES TO THE EXPOSED HEAT SLUG AS WELL AS THE TERMINAL.

4 RADIUS ON TERMINALS IS OPTIONAL.

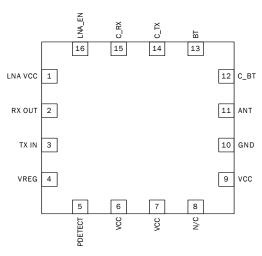






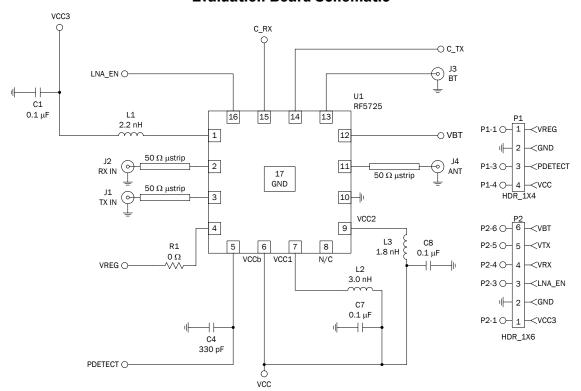


Pin Out





Evaluation Board Schematic





Theory of Operation

The RF5745 is an integrated front-end module (FEM) for high performance ZigBee® (802.15.4) and WiFi (802.11b/g) applications in the 2.4 GHz to 2.5 GHz ISM band. The FEM addresses the need for aggressive size reduction by integrating 50Ω matching networks to all RF ports and minimizing the number of external components. The FEM has integrated ZigBee® power amplifier, LNA, power detector, and some TX filtering. Also it is capable of switching between WiFi RX, WiFi TX, and simultaneous WiFi/BT Receive modes. The device is manufactured on GaAs HBT/pHEMT processes and is provided in a $3.00\,\mathrm{mmx}3.00\,\mathrm{mmx}0.45\,\mathrm{mm}$ 16-pin QFN package. This module meets or exceeds the front-end system requirements for $802.15.4\,\mathrm{and}$ 802.11b/g applications.

For best performance, the evaluation board layout should be copied as close as possible in particular the ground vias and bypassing components. Other configurations may work, but the design process is much easier and quicker if this recommendation is followed. Gerber files of the evaluation board can be provided upon request. The supply voltage lines should present an RF short to the FEM by using bypass capacitors on the $V_{\rm CC}$ traces.

The RF5745 is a very easy part to implement, but care on circuit layout and component selection is always advisable when designing circuits that operate at 2.5 GHz. Please contact RFMD Sales or Application Engineering for additional data and guidance. The RF5745 requires a single supply voltage (V_{CC}), a regulated current control voltage (V_{REG}) supply, and a switch control supply to simplify bias requirements.

802.11b/g and ZigBee® Transmit Path

The RF5745 has a typical gain of 31dB from 2.4GHz to 2.5GHz. This FEM is capable of delivering a typical output power of 24dBm to 25dBm when operating under the IEEE802.15.4 conditions. It is also capable of delivering 17dBm typical output power with a standard IEEE802.11g waveform and 20dBm with a standard IEEE802.11b waveform. Current control optimization is provided through the V_{RFG} pin which requires a regulated supply to maintain nominal current.

Out of Band Rejection

The RF5745 contains basic filtering components for the transmit path. Due to space constraints inside the module, filtering is limited to a few resonant poles. Additional filters may be needed outside the module depending upon the end-user's application.

Receive Path

While on receive mode, the RF5745 has a typical gain of 10dB and minimum insertion loss for the BT path. The RX port return loss is typically around 10dB. Depending on the application, if higher out of band rejection is needed beyond what the RF5745 can achieve, then additional external filters may be added. The RF5745 is designed so that the SP3T may act as a 3dB splitter when placed in WiFi RX and BT RX mode simultaneously. See logic control table for proper settings.



RF5745 Biasing Instructions:

- 802.11b/g and ZigBee® Transmit
 - · Connect the FEM to a signal generator at the input and a spectrum analyzer at the output.
 - Bias V_{CC} to 4.0V first with V_{REG}=0.0V
 - Refer to switch operational truth table to set the control lines at the proper levels for WiFi TX.
 - Turn on V_{REG} to 2.85 V (typ.). V_{REG} controls the current drawn by the 802.11b/g and ZigBee® power amplifier and the current should quickly rise to ~100 mA±20 mA for a typical part but it varies based on the output power desired. Be extremely careful not to exceed 3.4V on the V_{REG} pin or the part may exceed device current limits.
- 802.11 b/g and ZigBee® Receive
 - To Receive WiFi set the switch control lines per the truth table below.
- BluetoothTM Receive
 - To Receive *Bluetooth*TM set the switch control lines per the truth table below.

Switch Control Logic

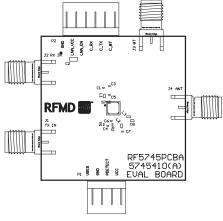
<u> </u>			
Mode	C_RX	C_TX	C_BT
Bluetooth TM	L	L	Н
WiFi Tx	L	Н	L
WiFi Rx	Н	L	L
WiFi Rx/BT	Н	L	Н

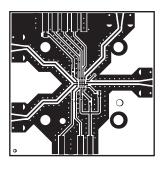
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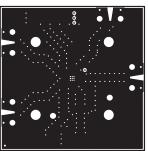


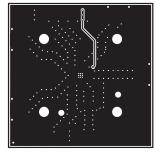
Evaluation Board Layout Board Size 1.5" x 1.5"

Board Thickness 0.032", Board Material FR-4, Multi-Layer











RF5745 Plots for IEEE802.11b

